

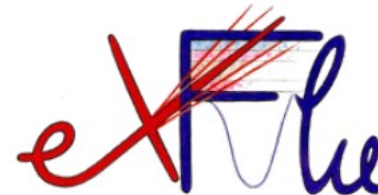


Detector R&D: tracking - LGAD (DRD3)

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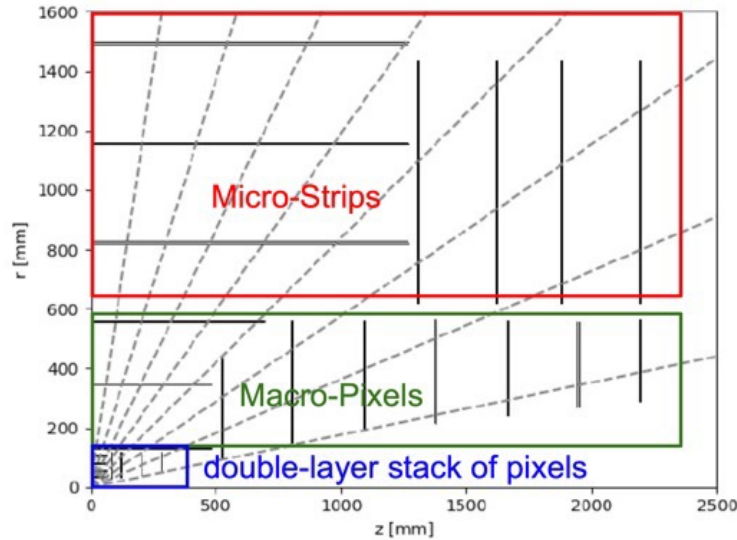


CSN5-4DSHARE



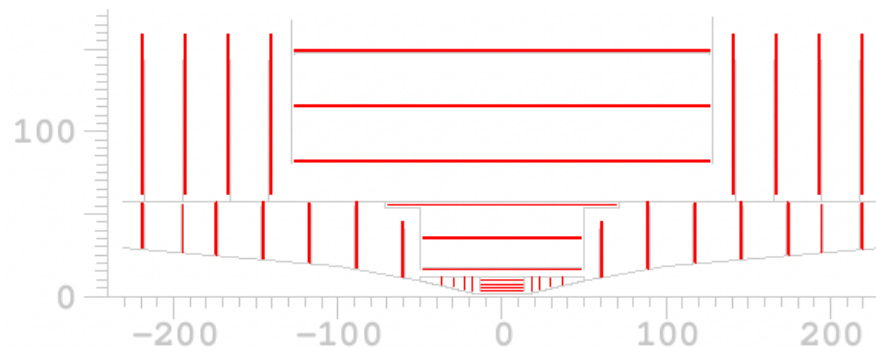
Tracker layout and sensors requirements

Original baseline tracking geometry and sensors requirements – design @ 3 TeV



	Vertex Detector	Inner Tracker	Outer Tracker
Cell type	pixels	macropixels	microstrips
Cell Size	$25\ \mu\text{m} \times 25\ \mu\text{m}$	$50\ \mu\text{m} \times 1\ \text{mm}$	$50\ \mu\text{m} \times 10\ \text{mm}$
Sensor Thickness	$50\ \mu\text{m}$	$100\ \mu\text{m}$	$100\ \mu\text{m}$
Time Resolution	30 ps	60 ps	60 ps
Spatial Resolution	$5\ \mu\text{m} \times 5\ \mu\text{m}$	$7\ \mu\text{m} \times 90\ \mu\text{m}$	$7\ \mu\text{m} \times 90\ \mu\text{m}$

New design to be finalized @ 10 TeV: geometry and sensors requirements



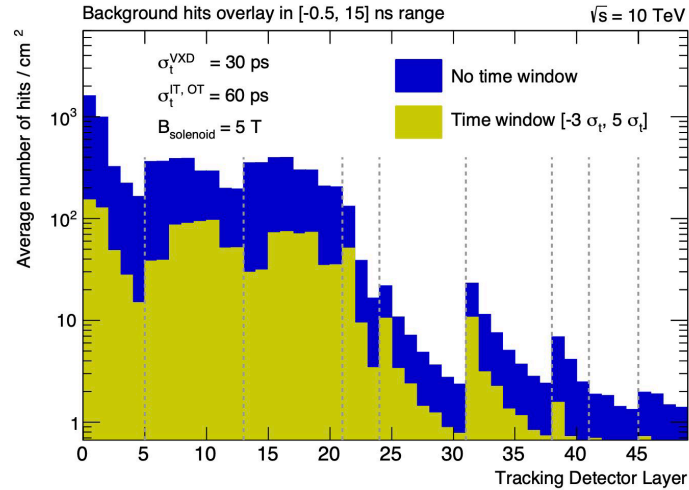
Fairly stringent requests for resolutions
Very high occupancy in the vertex detector

To be combined with:

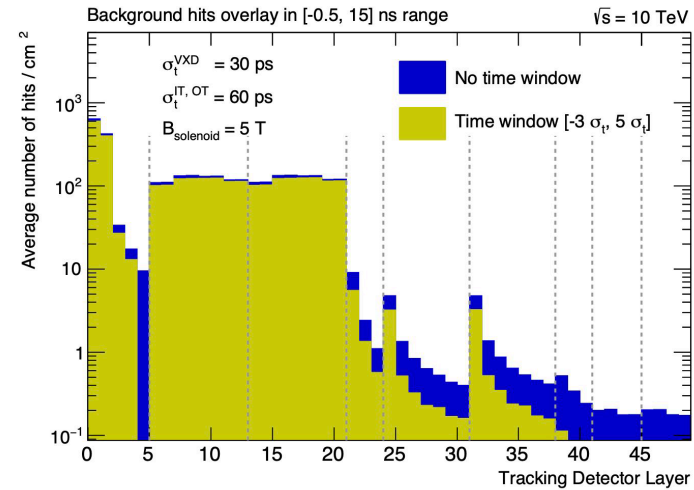
- As low as possible material budget
- As low as possible power consumption

Studies @ 10 TeV per bunch crossing

Beam Induced Background
(*asynchronous, diffused*)

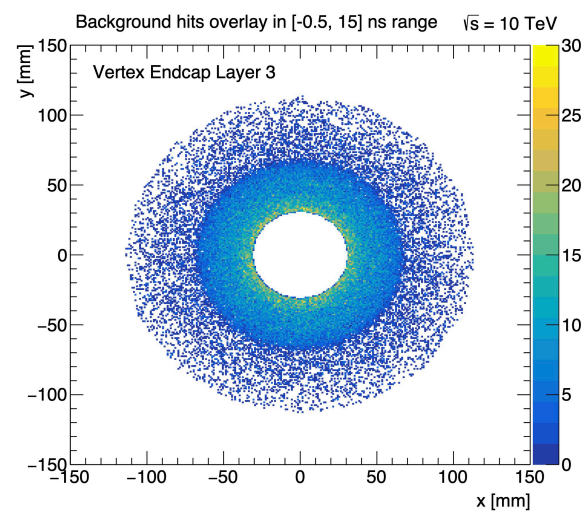
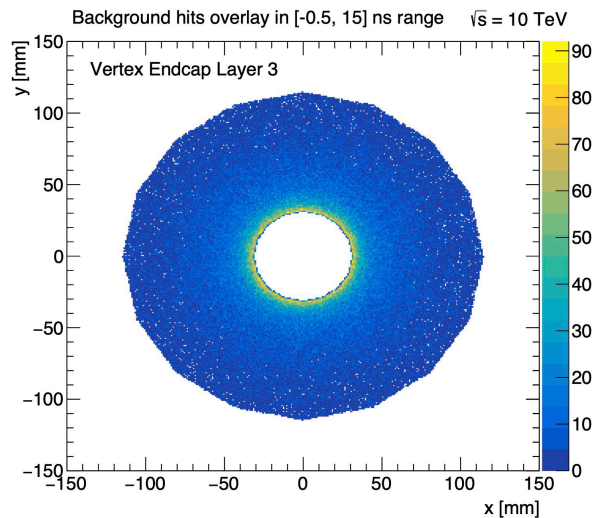


Incoherent Pair Production
(*synchronous, from IP*)



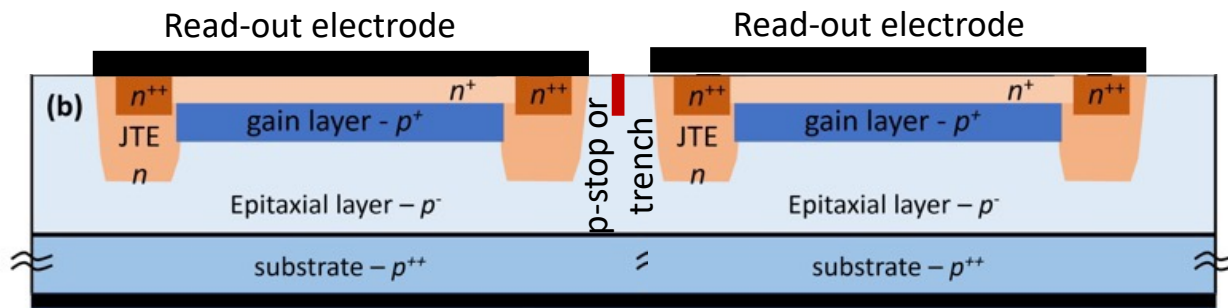
Timing
crucial to
reduce BIB

Incoherent
pair production
on-time



LGAD : a sensors technology candidate for the tracker

State of the art of LGAD technology
(technology chosen for CMS and ATLAS timing detectors)



Low Gain Avalanche Detectors (LGAD):

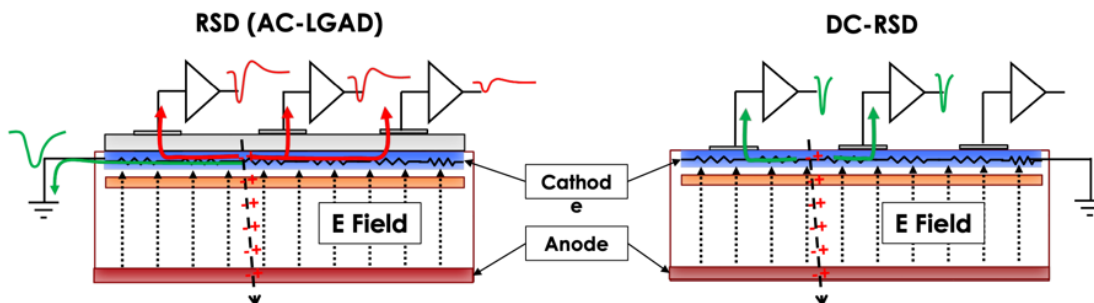
- Internal multiplication layer
- Large and fast signal (temporal resolution ~ 30 ps)
- Low active thickness (50 μm or less)
- moderate radiation hardness (up to $2\text{-}3 \cdot 10^{15}$ $n_{\text{eq}}/\text{cm}^2$)
- Pixel isolation (p-stop implant or trench)

The two parallel lines of R&D on LGAD technology

Resistive silicon detector (RSD)

RSD based is functionality on the signal sharing between read-out pads via a resistive read-out electrode.

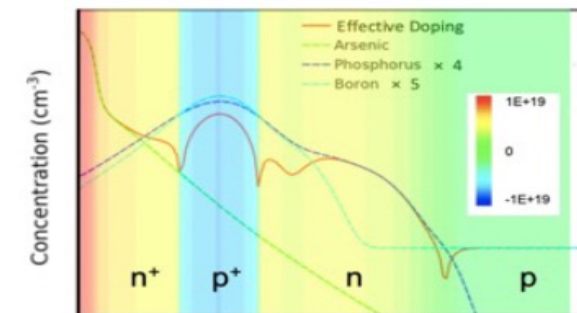
The signal sharing guarantees the reconstruction of the particle hit point with excellent precision.



Spatial resolution in RSD overcomes the limit of $\text{pitch}/\sqrt{12}$ from binary readout

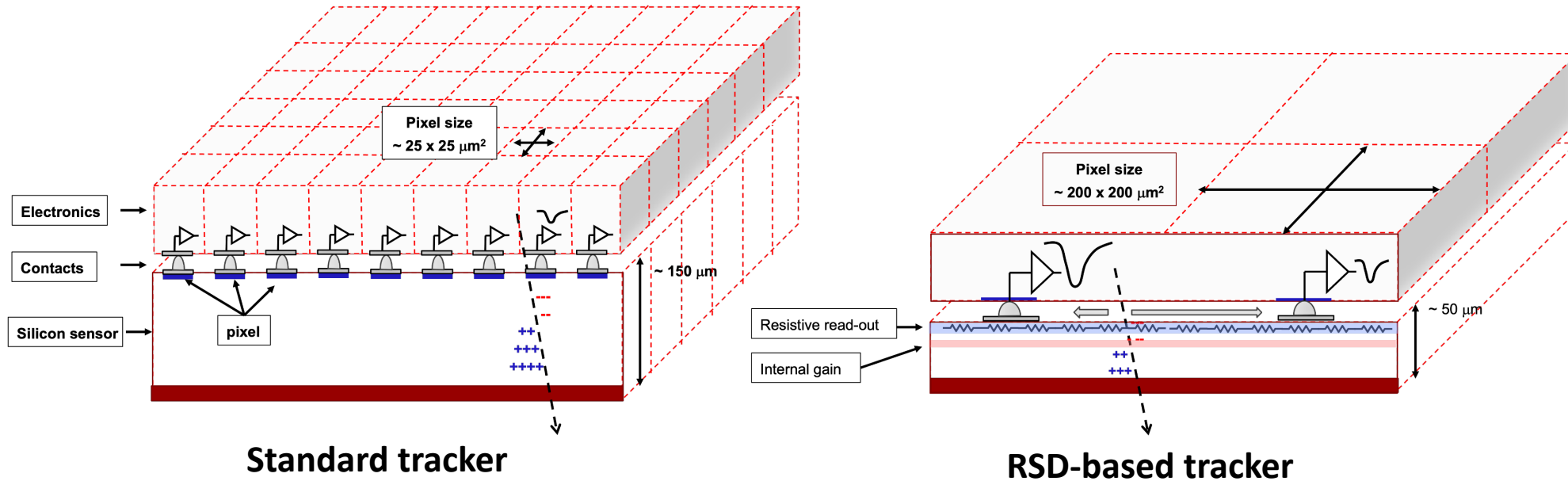
Compensated-LGAD

Improvement of the multiplication layer design to cope with fluences exceeding 10^{16} $n_{\text{eq}}/\text{cm}^2$



A completely new tracker based on RSD (AC or DC couple)

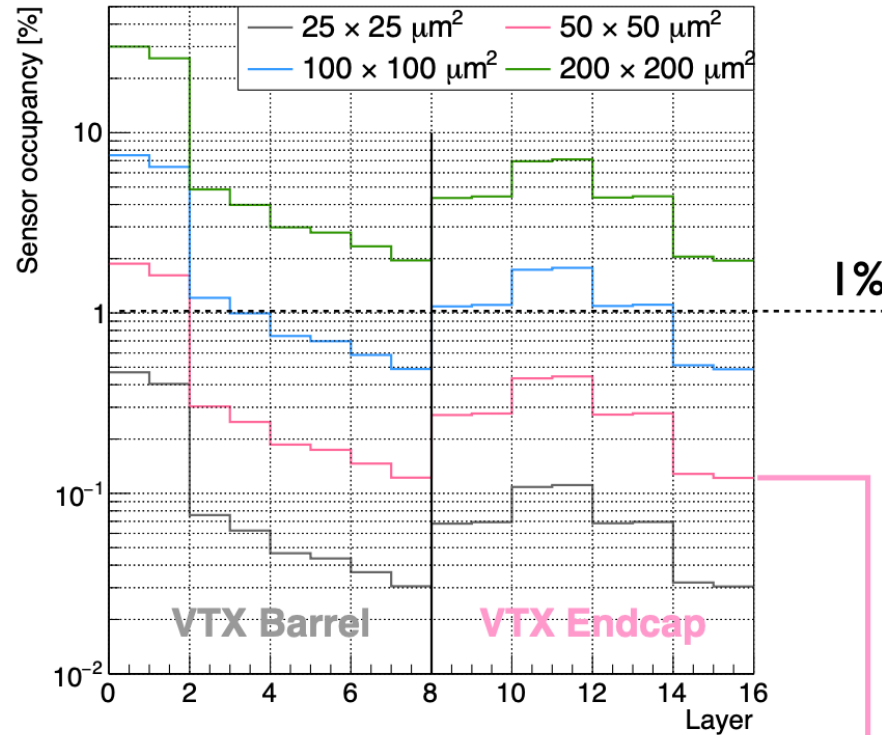
One of the candidate technology for the major part of the tracker



The design of a tracker based on RSD is truly innovative:

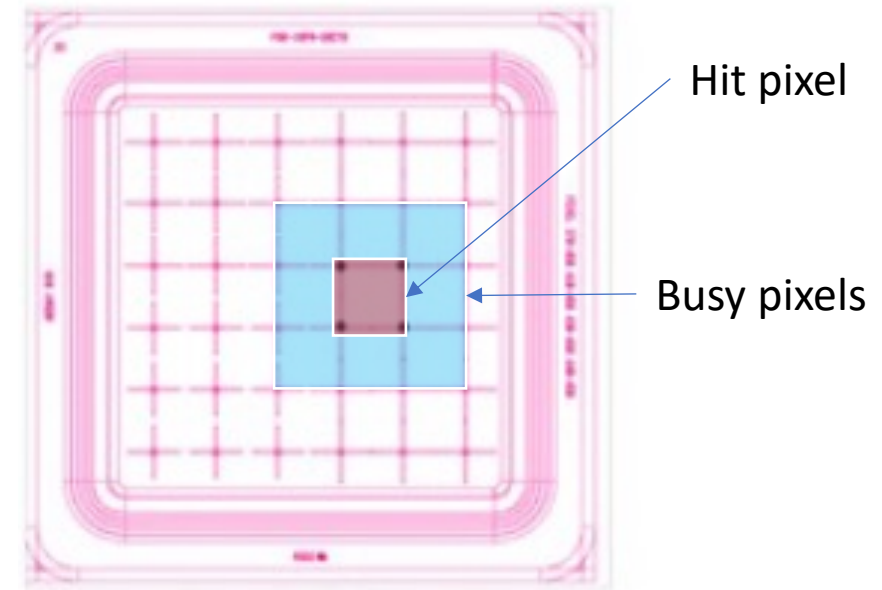
- It delivers ~ 20 - 30 ps temporal resolution
- For the same spatial resolution, the number of pixel is reduced by 50-100
- The electronic circuitry can be easily accomodated
- The power consumption is much lower, it might even be air cooled (~ 0.1 - 0.2 W/cm²)
- The sensors can be really thin

Occupancy



**Low Occupancy must be ensured to avoid pile-up effects
50x50 μm pads would be sufficient for most of the VTX**

Effective area for read out of a single hit is 3x3 pixels



Traditional trench-isolated LGADs could be more suitable for VTX

LGAD sensors towards 4D tracking

AC- and DC-Resistive Silicon Detector (RSD)

Projects involved RSD technology development:

- **RSD** (Grant giovani Gruppo V - from 2019-2021):
 - Demonstrator of AC-LGAD based on resistive read-out for 4D tracking
- **4D-Share** (Call Gruppo V and PRIN2022 - from 2023 to 2025):
 - Expected 2 productions of DC-RSD sensors
 - 1 year post-doc starting in April 2023
- **RadHard AC-LGAD** (RD50/DRD3 common project - from 2024):
 - An AC-LGAD production with the purpose of investigating and extending the radiation hardness of the RSD technology
- **FAST3-Amplifier** (RD50/DRD3 common project - from 2024):
 - Development of a multichannel amplification boards based on FAST3 ASIC, optimized to readout multi-channel LGAD prototypes (optimal in laboratory and test beam activities).

LGAD sensors towards 4D tracking

AC- and DC-Resistive Silicon Detector (RSD)

The main goals of these projects:

- Evolve the resistivity AC-LGAD design towards a DC-RSD design (4D-Share)
 - Controlled signal sharing in a predetermined number of pads to operate the device in high occupancy environments
- Extend of the radiation resistance of RSD technology up to fluence of $3 \cdot 10^{15} n_{eq}/cm^2$ (RadHard AC-LGAD project)

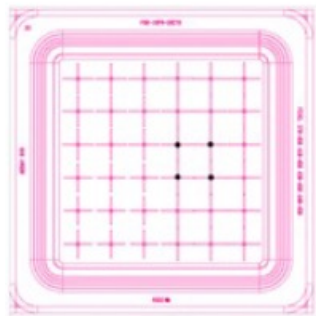
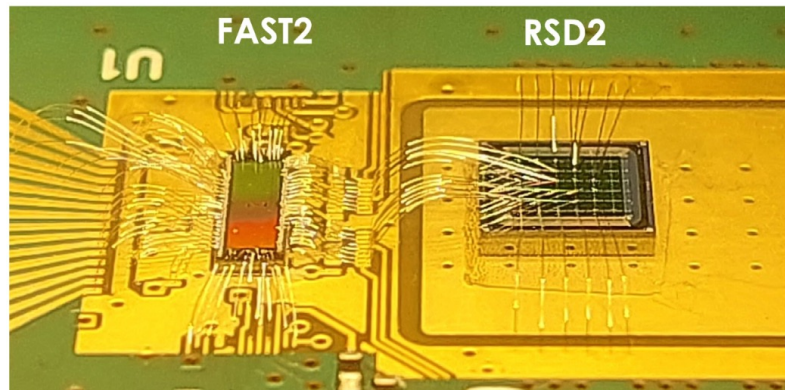
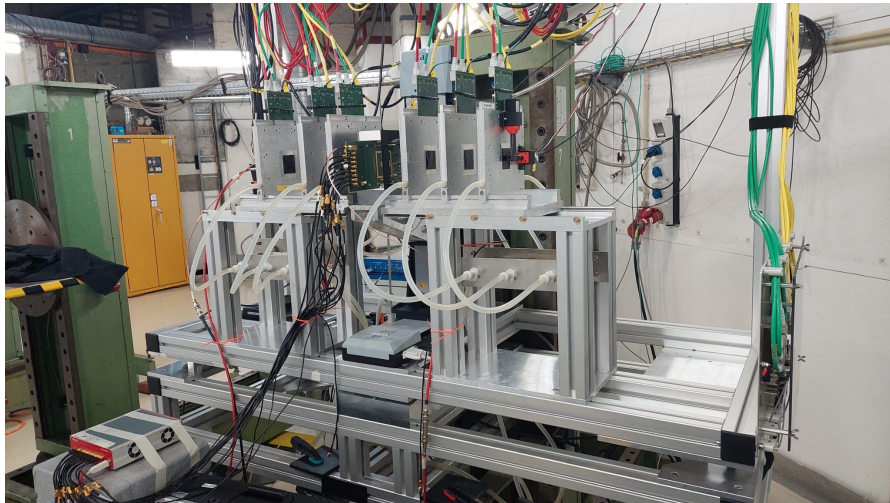
Outlook of the projects for the end of 2024 and 2025:

- The first DC-RSD batch is currently in production, it is expected in September 2024
- RadHard AC-LGAD production are expected for the end of 2025
 - The simulation of AC-LGAD including the Perugia radiation damage model is ongoing

AC-LGAD (RSD)

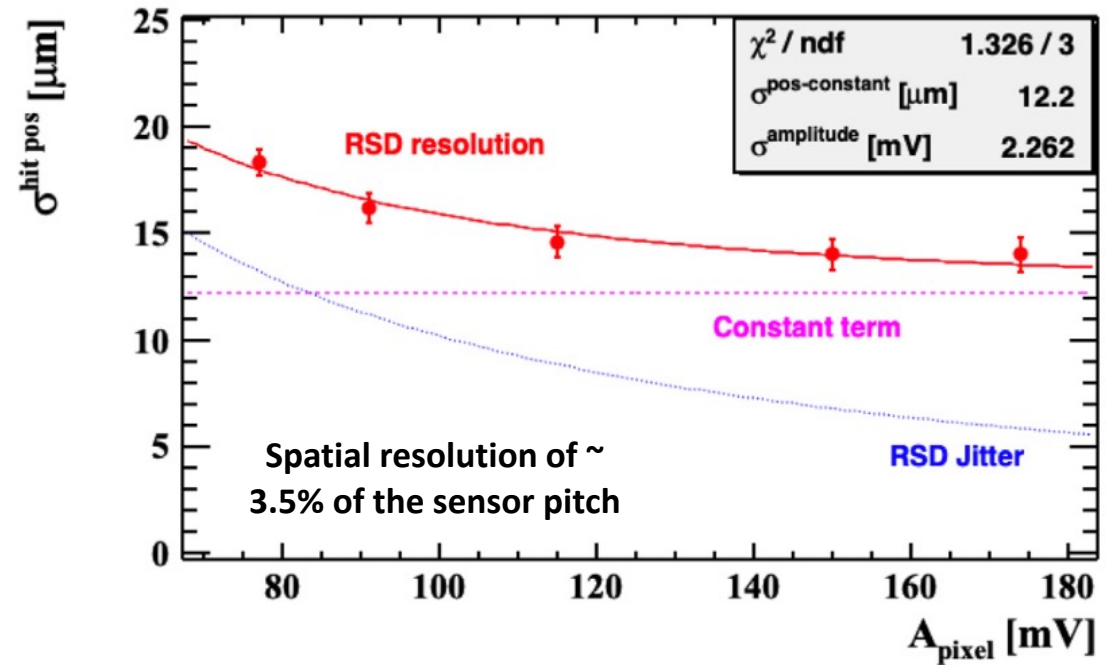
More significant experimental results

FBK-RSD2 sensor geometry tested in a beam test campaign in DESY



36 electrode
Pitch 450 μ m

Position Resolution as a function of the sum of the signal amplitudes seen by the electrodes at the 4 corners of the pixel



Charge imbalance has been used as reconstruction method

$$x^{\text{meas}} = x_0 + \frac{\text{pitch}}{2} * \frac{(A_3 + A_4) - (A_1 + A_2)}{\sum_1^4 A_i}$$

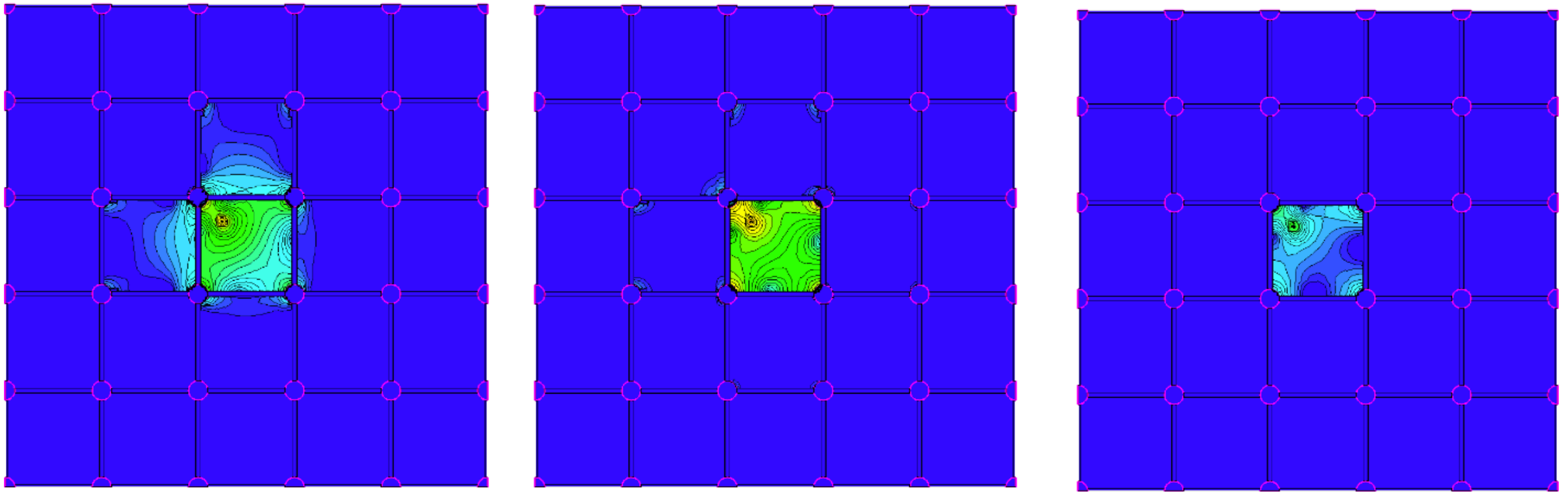
$$y^{\text{meas}} = y_0 + \frac{\text{pitch}}{2} * \frac{(A_1 + A_3) - (A_2 + A_4)}{\sum_1^4 A_i}$$

DC-Resistive Silicon Detector (RSD)

More significative simulated results

TCAD simulation of 6x6 pixel matrix DC-RSD

(Time evolution of the charge density generated by the passage of a particle)



- Pixel isolation with trenches
- each read-out electrode shared between 4 pixels
- Hit position close the top-left electrode in the central pixel

LGAD sensors for extreme fluences ($10^{16} - 10^{17} n_{eq}/cm^2$)

Projects

Projects involved in LGAD for extreme fluence:

- **eXFlu** (Grant giovani Gruppo V - from 2020-2022):
 - Demonstrator of the compensated-LGAD technology
- **eXFlu-Innova** (AIDAInnova project from 2022 to 2025):
 - co-funding first prototype of compensated-LGAD and p-in-n LGAD, preparatory to the design of compensated-LGAD
 - 2 years post-doc starting in September 2023
- **ComonSens** (PRIN2022 - from 2023 to 2025):
 - co-funding of p-in-n LGAD preparatory to the design of compensated-LGAD
 - 2 years post-doc starting in July 2024
- **Complex** (ERC - from 2024 to 2029):
 - Funding of 3 productions of Compensated LGAD for extreme fluences
- **Partial Activated Boron** (RD50/DRD3 common project - from 2024)

All ongoing project involve the INFN/CNR Perugia Groups and FBK

LGAD sensors for extreme fluences ($10^{16} - 10^{17} n_{eq}/cm^2$)

The main goal of these projects is to produce thin LGAD sensors able to operating up to fluence of $10^{17} n_{eq}/cm^2$

- Simulation and design of a reliable and radiation hardness of multiplication layer based on compensation technology
- Design of the sensor termination structures able to operate above $10^{16} n_{eq}/cm^2$
- Development of a radiation damage model for extreme fluences
- Measurements of silicon sensors properties irradiated over $10^{16} n_{eq}/cm^2$

Outlook of the projects for the end of 2024 and 2025:

- A p-in-n LGAD production expected for the Q4/2024 – Q1/2025 (from eXFlu-innova and ComonSens projects)
 - Device simulations have been finalized
 - The design of the production layout is ongoing
- A compensated-LGAD production expected for the end of 2025

LGAD sensors for extreme fluences ($10^{16} - 10^{17} n_{eq}/cm^2$)

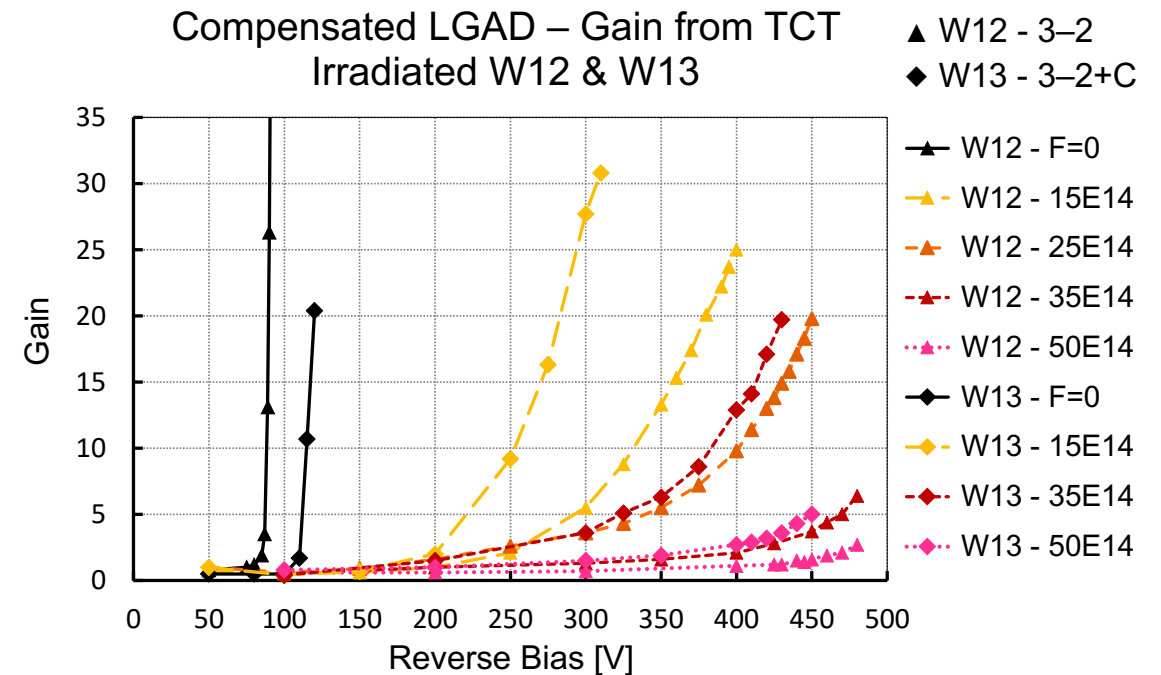
More significative experimental results

eXFlu-batch

Demonstrator of Compensated-LGAD technology delivered in 2022



An extensive characterization with pulsed IR laser was conducted in laboratory on irradiated compensated-LGAD



For the first time an LGAD irradiated at $5 \cdot 10^{15}$ provide 10 fC of charge

Conclusion and outlook for 2024 and 2025

Sensor batches expected in 2024 and 2025:

- DC-RSD in Q4/2024
 - p-in-n LGAD in Q4/2024 – Q1/2025
 - First CompleX batch in Q4/2025
 - Partial Activated Boron in Q4/2025
 - RadHard AC-LGAD in Q4/2025
- Extensive laboratory testing campaigns to select most promising sensor design and layout
 - Several beam test campaign are and will be scheduled at the end of 2024 and in 2025, at DESY and CERN facilities



DESY 2 Test Beam Schedule 2024 - Status from 22/JUL/2024

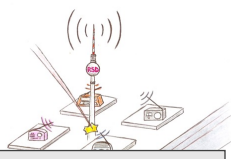


DESY 2 Test Beam Coordinators: Ralf Diener, Norbert Meyners, Marcel Stanitzki

Startdate	Week	TB21	T	TB22	T	TB241	T	TB24	T
09.12.2024	50	LHCb-MightyPix	X	DCRSD	X			CMS ETL ETROC	X
16.12.2024	51	LHCb-MightyPix	X	Telescope-Dev	X			EXFLU	
23.12.2024	52	Shutdown		Shutdown		Shutdown		Shutdown	

Backup

Matching UFSD-RSD capabilities to the muColl requests



		cell size	sensor thickness	time resolution	spatial resolution	number of cells
VXD	B	25 μm \times 25 μm pixels	50 μm	30 ps	5 μm \times 5 μm	729M
	E	25 μm \times 25 μm pixels	50 μm	30 ps	5 μm \times 5 μm	462M

High occupancy and levels.

TI-LGAD can be used up to $1\text{-}2\text{E}15$ n/cm²

R&D in radiation harness needed to cover the full radiation field

IT	B	50 μm \times 1 mm macropixels	100 μm	60 ps	7 μm \times 90 μm	164M
	E	50 μm \times 1 mm macropixels	100 μm	60 ps	7 μm \times 90 μm	127M

Low occupancy and radiation levels. Ideal for macro-pixels.

Pixel size, spatial, and temporal resolutions are a perfect fit for present RSD technology

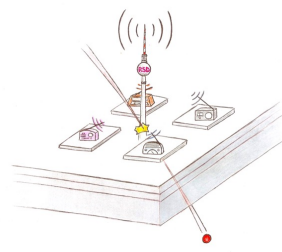
RSD will strongly reduce the number of pixels

OT	B	50 μm \times 10 mm microstrips	100 μm	60 ps	7 μm \times 90 μm	117M
	E	50 μm \times 10 mm microstrips	100 μm	60 ps	7 μm \times 90 μm	56M

Very Low-occupancy and radiation levels. Long strips do not provide accurate temporal resolution.

Propose to replace it with **RSD macro pads**

Conclusions



UFSD and RSD offer very good combined spatial and temporal performances
 These designs are a good fit to the need of the muColl design

		cell size	sensor thickness	time resolution	spatial resolution	number of cells
VXD	B	25 μm \times 25 μm pixels	50 μm	30 ps	5 μm \times 5 μm	729M
	E	25 μm \times 25 μm pixels	50 μm	30 ps	5 μm \times 5 μm	462M
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OT	B	50 μm \times 10 mm microstrips	100 μm	60 ps	7 μm \times 90 μm	117M
	E	50 μm \times 10 mm microstrips	100 μm	60 ps	7 μm \times 90 μm	56M

Proposed detector

Cell size	Number of cells	Thickness	Detector
To be decided		50 μm	TI_LGAD
200 μm x 2 mm	1/8 # of present design	50 μm	RSD
200 μm x 2 mm	Similar to the present design	50 μm	RSD

Very difficult (impossible?) to achieve good timing with strips
 Better to use macro-pads?

In Torino we are continuing the development of TI-LGAD and RSD for applications to the muColl tracker